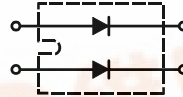


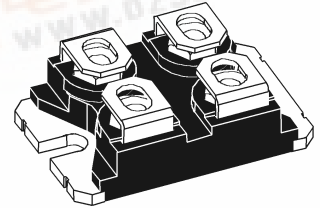
**Power Schottky Rectifier**

**$I_{FAV} = 2x60 A$**   
 **$V_{RRM} = 45 V$**   
 **$V_F = 0.66 V$**

$V_{RSM}$ V	$V_{RRM}$ V	Type
45	45	DSS 2x61-0045A



miniBLOC, SOT-227 B



Symbol	Conditions	Maximum Ratings	
$I_{FRMS}$		100	A
$I_{FAVM}$	$T_C = 105^\circ C$ ; rectangular, $d = 0.5$	60	A
$I_{FAVM}$	$T_C = 105^\circ C$ ; rectangular, $d = 0.5$ ; per device	120	A
$I_{FSM}$	$T_{VJ} = 45^\circ C$ ; $t_p = 10$ ms (50 Hz), sine	800	A
$E_{AS}$	$I_{AS} = 20$ A; $L = 180$ $\mu H$ ; $T_{VJ} = 25^\circ C$ ; non repetitive	57	mJ
$I_{AR}$	$V_A = 1.5 \cdot V_{RRM}$ typ.; $f = 10$ kHz; repetitive	2	A
$(dv/dt)_{cr}$		1000	V/ $\mu s$
$T_{VJ}$		-40...+150	$^\circ C$
$T_{VJM}$		150	$^\circ C$
$T_{stg}$		-40...+150	$^\circ C$
$P_{tot}$	$T_C = 25^\circ C$	150	W
$V_{ISOL}$	50/60 Hz, RMS $I_{ISOL} \leq 1$ mA	2500	V~
$M_d$	mounting torque (M4) terminal connection torque (M4)	1.1-1.5/9-13 1.1-1.5/9-13	Nm/lb.in. Nm/lb.in.
Weight	typical	30	g

**Features**

- International standard package miniBLOC
- Isolation voltage 2500 V~
- UL registered E 72873
- 2 independent Schottky diodes in 1 package
- Very low  $V_F$
- Extremely low switching losses
- Low  $I_{RM}$ -values

**Applications**

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

**Advantages**

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

Dimensions see outlines.pdf

Symbol	Conditions	Characteristic Values	
		typ.	max.
$I_R$ ①	$T_{VJ} = 25^\circ C$ $V_R = V_{RRM}$ $T_{VJ} = 125^\circ C$ $V_R = V_{RRM}$	2	20
$V_F$	$I_F = 60$ A; $T_{VJ} = 125^\circ C$	0.66	V
	$I_F = 60$ A; $T_{VJ} = 25^\circ C$	0.74	V
	$I_F = 120$ A; $T_{VJ} = 125^\circ C$	0.86	V
$R_{thJC}$ $R_{thCH}$	0.1	0.8	K/W K/W

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %  
 Data according to IEC 60747 and per diode unless otherwise specified

IXYS reserves the right to change limits, Conditions and dimensions.

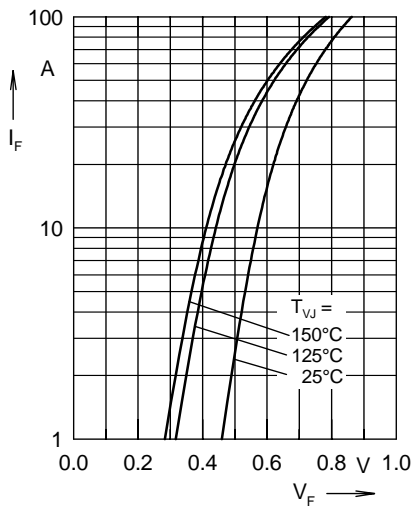


Fig. 1 Maximum forward voltage drop characteristics

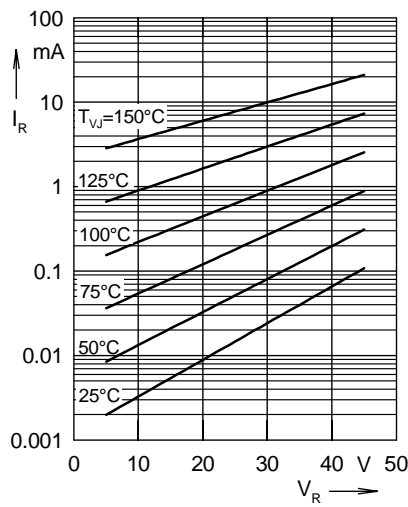


Fig. 2 Typ. value of reverse current  $I_R$  versus reverse voltage  $V_R$

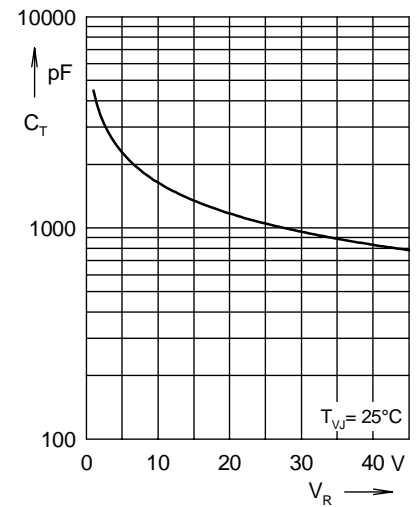


Fig. 3 Typ. junction capacitance  $C_T$  versus reverse voltage  $V_R$

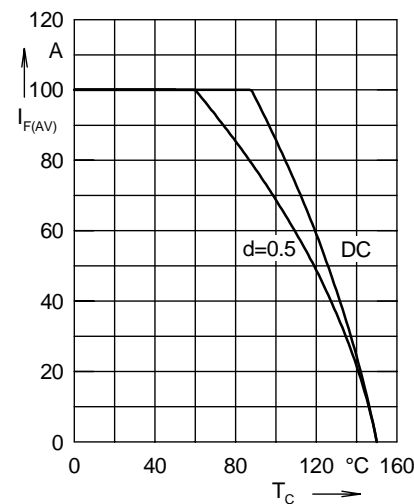


Fig. 4 Average forward current  $I_{F(AV)}$  versus case temperature  $T_C$

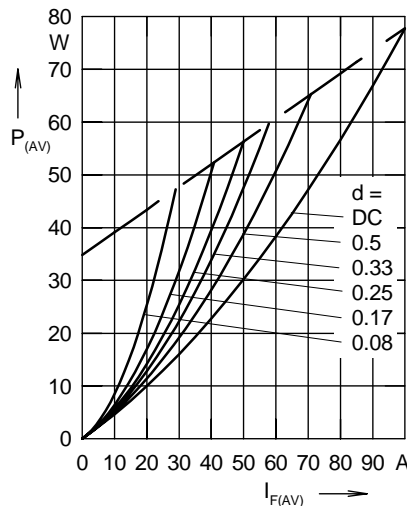


Fig. 5 Forward power loss characteristics

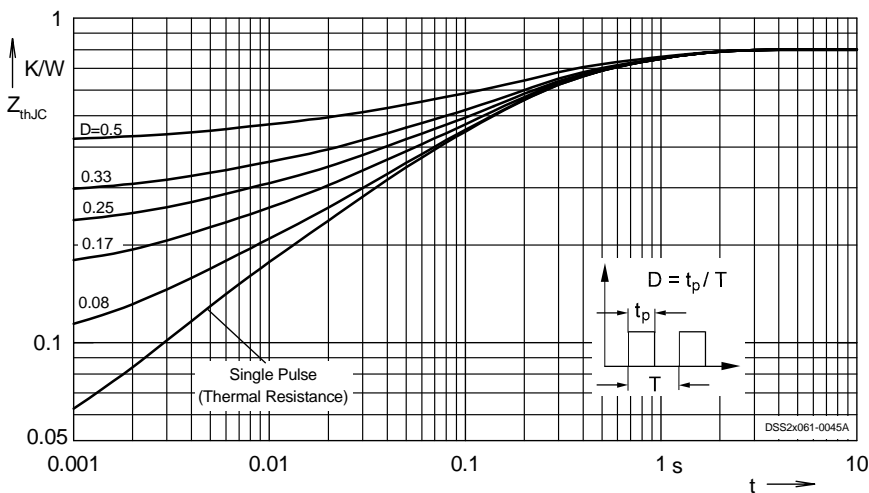


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode